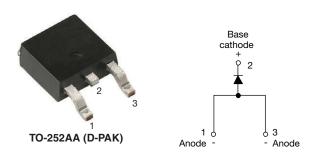


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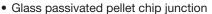
Vishay Semiconductors

Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY						
Package	TO-252AA (D-PAK)					
I _{F(AV)}	8 A					
V _R	200 V, 400 V, 600 V					
V _F at I _F	1.2 V					
I _{FSM}	150 A					
t _{rr}	55 ns					
T _J max.	150 °C					
Diode variation	Single die					
Snap factor	0.5					

FEATURES







ROHS

 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-8EWF..SPbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This series is designed and qualified for industrial level.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Sinusoidal waveform	8	А					
V _{RRM}		200 to 600	V					
I _{FSM}		150	А					
V _F	8 A, T _J = 25 °C	1.2	V					
t _{rr}	1 A, 100 A/μs	55	ns					
TJ	Range	-40 to +150	°C					

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-8EWF02SPbF	200	300						
VS-8EWF04SPbF	400	500	3					
VS-8EWF06SPbF	600	700						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	$T_C = 96$ °C, 180° conduction half sine wave	8					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	125	Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	150					
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s				
Waximum i-t for fusing		10 ms sine pulse, no voltage reapplied 110		A-5				
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s				

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VS-8EWF..SPbF Soft Recovery Series

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C	8 A, T _J = 25 °C					
Forward slope resistance	r _t	T - 150 °C	16	mΩ				
Threshold voltage	V _{F(TO)}	1J = 150 C	T _J = 150 °C					
Maximum reverse leakage current		$T_J = 25 ^{\circ}\text{C}$ $V_B = \text{Rated } V_{BBM}$		0.1	mA			
iviaximum reverse leakage current	IRM	T _J = 150 °C	VR = nated VRRM	3	IIIA			

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •			
Reverse recovery time	t _{rr}	I _σ at 8 Δ .	200	ns	I _{FM}			
Reverse recovery current	I _{rr}	- I _F at 8 A _{pk} 25 Α/μs	2.6	А	$t_a \mid t_b$			
Reverse recovery charge	Q _{rr}	T _J = 25 °C	0.25	μC	di di Q,,			
Snap factor	S		0.5		dt I_{rr}			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W			
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} (1)		50	C/VV			
Approximate weight			1	g			
Approximate weight			0.03	oz.			
Marking device		Case style TO-252AA (D-PAK)	8EWF	-06S			

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

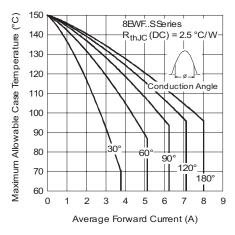


Fig. 1 - Current Rating Characteristics

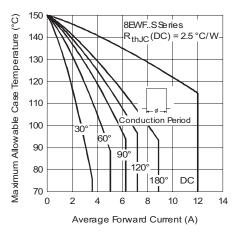


Fig. 2 - Current Rating Characteristics

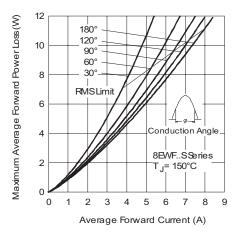


Fig. 3 - Forward Power Loss Characteristics

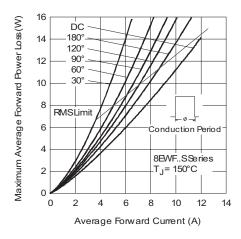


Fig. 4 - Forward Power Loss Characteristics

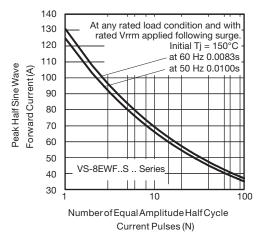


Fig. 5 - Maximum Non-Repetitive Surge Current

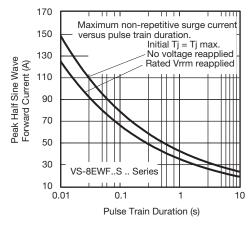


Fig. 6 - Maximum Non-Repetitive Surge Current

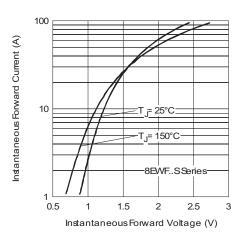


Fig. 7 - Forward Voltage Drop Characteristics

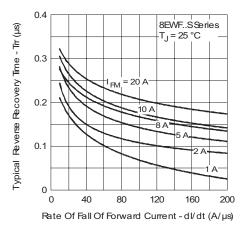


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

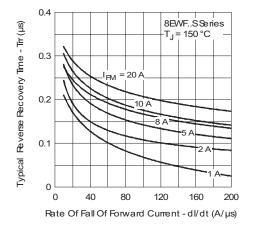


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

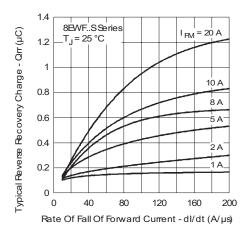


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

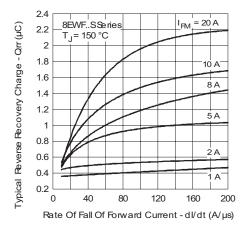


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

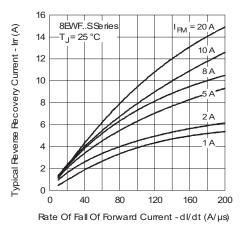


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

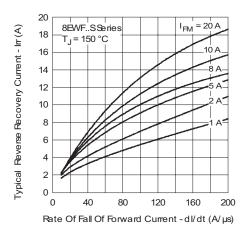


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

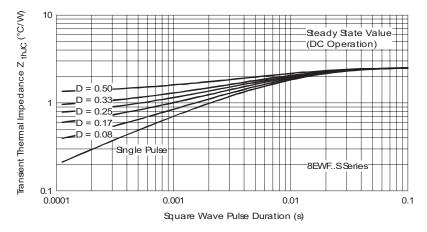
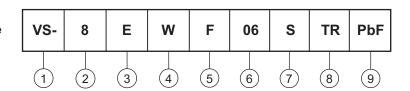


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V 04 = 400 V

- Voltage code x 100 = V_{RRM}

06 = 600 V

7 - S = surface mountable

- • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

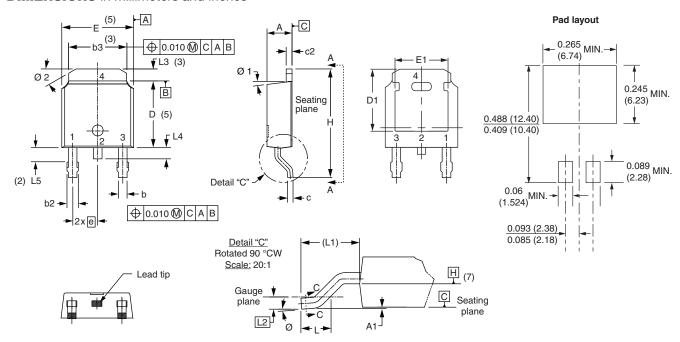
9 - PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95016</u>						
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95551					



D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIN	1ETE
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	М
А	2.18	2.39	0.086	0.094			е	2.29	BSC
A1	-	0.13	-	0.005			Н	9.40	10
b	0.64	0.89	0.025	0.035			L	1.40	1
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC
С	0.46	0.61	0.018	0.024			L3	0.89	1
c2	0.46	0.89	0.018	0.035			L4	-	1
D	5.97	6.22	0.235	0.245	5		L5	1.14	1
D1	5.21	-	0.205	-	3		Ø	0°	1
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	1
E1	4.32	-	0.170	-	3		Ø2	25°	3

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108	REF.	
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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